Method for measurement of the density of thin films of small organic molecules

Hai-Feng Xiang
Department of Electrical & Electronic Engineering, Department of Chemistry and HKU-CAS Joint Laboratory on New Materials, The University of Hong Kong, Pokfulam Road, Hong Kong SAR, China

Zong-Xiang Xu, V. A. L. Roy, and Chi-Ming Che
Department of Chemistry and HKU-CAS Joint Laboratory on New Materials, The University of Hong Kong, Pokfulam Road, Hong Kong SAR, China

P. T. Lai
Department of Electrical & Electronic Engineering, The University of Hong Kong, Pokfulam Road, Hong Kong SAR, China

(Received 26 July 2006; accepted 1 February 2007; published online 21 March 2007)

An accurate and sensitive method is reported to measure the thin-film density of vacuum-deposited, small-molecular organic semiconductor materials. A spectrophotometer and surface profiler had been used to determine the mass and thickness of organic thin film, respectively. The calculated density of tris-(8-hydroxyquinolato) aluminum (Alq₃) thin film was 1.31±0.01 g/cm³. Vacuum pressures and thin-film growth rates are found to have less impact on the thin-film density of organic material. However, the thin-film density of organic material strongly depends on its chemical structure and molecular weight. Specifically, the chemical structure determines the density of organic material that affects the molecular volume and intermolecular stacking. © 2007 American Institute of Physics. [DOI: 10.1063/1.2712932]

I. INTRODUCTION

Density (ρ) is an important parameter of materials and defined as mass (m) per unit volume (V). In order to measure the density, the volume of the material has to be homogenous. Therefore, it is easy to measure the density of homogenous materials such as metals, gases, and liquids, and their densities are available in the literature. However, most of the small-molecular organic materials are in powder at room temperature, which is not homogenous in volume. The traditional way to determine the density of organic materials is to grow a single crystal of the particular material and measure its density by x-ray diffraction. A potential problem could be, through this method, several values of density corresponding to different crystal isostructures depending on the densities of crystal growth. This problem can be solved by the growth of uniform organic thin films using thermal evaporation under high vacuum. It is obvious that the calculated density from a single crystal varies from the thin film of the same material due to their different molecular arrangements.

Since the 1980s, high-vacuum technology has been facilitating the realization of organic electronic devices, such as organic light-emitting devices (OLEDs), organic photovoltaic (PV) cells, organic lasers, and organic thin-film transistors (OTFTs). During the growth of vacuum-deposited organic films, the film thickness and growth rate are detected by the crystal thickness monitor. However, density is one of the parameters that determines the thickness and growth rate of the organic material. In addition, to improve device performance, doping technology has been widely adopted in OLEDs and organic PV cells. In this case, the densities of both guest and host are required to calculate the correct doping concentration.

This report describes an accurate method to find out the density of organic thin film based on small-molecular organic materials. We used spectrophotometric determination to determine the mass of organic thin film, and surface profiler to detect the film thickness. Then, the density of the film was calculated by

$$\rho = \frac{m}{V} = \frac{m}{WLT}.$$  

where W is the width of the film, L is the length, and T is the thickness. The effects of vacuum pressure and thin-film growth rate on the density were also explored. To the best of our knowledge, this is the first report that has been published to determine the thin-film density of small-molecular organic materials.

II. EXPERIMENTAL METHODS

All organic materials (98%−99%) and solvents (analytical grade) were purchased from Aldrich. A glass substrate was cleaned by the following method: soaked in a water-based detergent by sonication for 10 min at 60 °C; rinsed with de-ionized (DI) water; sonicated in DI water; sonicated in ethanol, toluene, and acetone for 10 min at 60 °C, respectively, in three cycles; rinsed with DI water; dried with a nitrogen blowgun; heated at 120 °C for 2 h in vacuum;
cleaned in UV ozone for 10 min. All organic materials were purified by vacuum sublimation before use. Organic thin films (100−400 nm) were deposited (0.2−4.0 Å/s) on a cleaned glass substrate by using a shadow mask in a high-vacuum evaporation system (BOC Edwards Auto 306). The deposited organic thin films had a W and L of 2.0 cm. The thickness and growth rate of the thin films were detected by a quartz crystal thickness monitor (BOC Edwards FTM7). The thickness of as-deposited thin films was determined by a Sloan Dektak3 ST surface profiler. In order to avoid heat radiation, which affects the amorphous film quality of the organic thin film, the distance between the thermal evaporation crucible and the substrate was kept up to 50 cm.

A standard curve of organic material was plotted between the absorbance at maximum absorption wavelength ($\lambda_{\text{max}}$) versus its corresponding concentration in organic solvent. To measure the mass of vacuum-deposited organic thin films, the substrate containing the thin films was dipped into the particular organic solvent (10−25 ml), dissolved by sonication, diluted to appropriate concentration (absorbance in the range of 0.2−0.7), and their absorbances were measured by a Perkin-Elmer Lambda 19 UV-visible spectrophotometer. The unknown mass/concentration of an organic material was extracted from its standard curve, and the density was calculated by Eq. (1).

### III. RESULTS AND DISCUSSION

Figure 1 shows the chemical structures of the organic materials used in this study: 1,10-Phenanthroline (Phen), Bathophenanthroline (BPhen), 4,7-Dimethy-1,10-phenanthroline (DMPhen), 2,9-dimethyl-4,7-diphenyl-1,10-phenanthroline (BCP), 4,4′-N,N′-dicarbazole-biphenyl (CBP), N,N′-diphenyl-N,N′-bis(3-methylphenyl)(1,10-biphenyl)-4,4′-diamine (TPD), N,N′-bis(naphthyl)-N,N′-diphenyl-1,1′-biphenyl-4,4′-diamine (NPB), tris-(8-hydroxyquinolato) aluminum (Alq3), 2-(4-biphenyl)-5-(4-tert-butylphenyl)-1,3,4-oxadiazole (r-PBD), mesotetraakisphenyl porphyrin ($H_2$TPP), platinum(II) mesotetraakisphenyl porphyrin (PtTPP), phthalocyanine (H$_2$Pc), copper(II) phthalocyanine (CuPc), pentacene, and fullerene (C$_{60}$). Most of them are organic semiconductors, widely used in OLEDs, organic PV cells, organic lasers, or OTFTs. All these π-conjugated organic semiconductors have a strong absorption in the UV-visible region. Therefore, a spectrophotometric determination based on the Beer-Lambert law is a simple, accurate, and sensitive method for finding the concentration of these organic semiconductors in solution.

Spectrophotometric determination is based on the absorption of light by an analyte or sample. In any case, the absorbance $A$ of a sample follows the Beer-Lambert law,

$$A = \varepsilon l c_m = \varepsilon l m = \frac{\varepsilon l m}{MV} = \frac{\varepsilon l m}{M V'} = k c_m,$$

(2)

where $\varepsilon$ is the molecular extinction coefficient, $c_m$ is the molecular concentration, $m$ is the mass concentration, $M$ is the molecular weight of absorbing species, $V$ is the volume of the solution, and $l$ (1.0 cm) is the absorption path length. The absorbance is usually limited to less than 1.0 unless the Beer-Lambert law breaks down due to aggregate formation at high concentration. Since $A$ is proportional to $c_m$, it is possible to create a linear plot for absorbance versus concentration when a set of standards of known concentration is measured. This is termed as the standard curve. An equation for this line can be derived and the concentrations of organic semiconductors could be quantitatively determined.

The first efficient low-voltage-driven OLED, demonstrated by Tang,$^7$ was based on Alq$_3$. Since then, Alq$_3$ has been widely used as electron-transporting material, green...
fluorescent emitter, and host material for various dyes to tune the emission color from green to red. Due to its thermal and morphological stabilities, it is feasible to form a good-quality thin film by vacuum deposition. Hence, we use Alq₃ as an example to explain the method for obtaining the thin-film density. In addition, the effects of vacuum pressure and thin-film growth rate on the thin-film density have been explained here.

Figure 2(a) illustrates the absorption spectrum of Alq₃ at different concentrations in a solution of CHCl₃. The absorbance (λ_max = 387 nm) of Alq₃ was found to be proportional to its concentration. The standard curve for Alq₃ exhibited in Fig. 3 shows a good linearity with a correlation coefficient (R) of 0.9999. Figure 2(b) depicts absorbance at λ_max of solutions, which were obtained by diluting vacuum-deposited Alq₃ thin films having thicknesses of 85, 183, and 363 nm deposited at a constant growth rate of 1 Å/s at 1.0 × 10⁻⁶ Torr. The calculated density for the 85-, 183-, and 363-nm Alq₃ films is 1.31, 1.32, and 1.29 g/cm³, respectively, revealing high reproducibility and accuracy for this determination.

Figure 4 shows the surface-scanning profiles of four 200-nm-thick Alq₃ thin films, which were grown at a constant growth rate of 1.0 Å/s under different vacuum pressures. 1.0 × 10⁻⁶, and 1.0 × 10⁻⁵ Torr, respectively. It has been observed that the vacuum pressure had a strong impact on the surface and profile quality of the thin films. Smaller roughness and sharper profile are formed under higher vacuum. In contrast, the growth rate (0.2–4.0 Å/s under a high vacuum of 1.0 × 10⁻⁶ Torr) had less effect on the surface and profile quality of the thin films. However, the overall impact of vacuum pressure and growth rate was small (<2%) on the density of the thin films. This can be explained by two reasons: (1) The step (700 μm at 5.0 × 10⁻⁵ Torr and 100 μm at 1.0 × 10⁻⁶ Torr in Fig. 4) profile is much smaller than the length (2.0 cm) or width (2.0 cm) of the thin films. (2) Even though the roughness is slightly larger (100 Å at 5.0 × 10⁻⁵ Torr and 50 Å at 1.0 × 10⁻⁶ Torr) in comparison with the thickness (~200 nm) of the thin films, the effect could be reduced by calculating the mean thickness or increasing the thickness during the growth of the thin films.

Figure 3 shows a good linearity with a correlation coefficient of 0.9999. Figure 2 illustrates the absorption spectrum of Alq₃ at 17,18

\[ A = -0.00310 + 15.7 \times c \]

\[ R = 0.9999 \]

\[ m = (A - 0.00110) \times V, \]

and then

\[ \rho = \frac{m}{V} = \frac{(A - 0.00110) \times V}{WLT}. \]

Therefore, the quantitative uncertainty (σ) of this measurement might be contributions from uncertainties in the (1) film thickness (σ_f = 0.30%); (2) film length (σ_l = 0.29%) and width (σ_w = 0.29%); (3) concentration of the dissolved film in the liquid, which is calculated from its absorbance (σ_A = 0.19%); (4) volume of the liquid (σ_V = 0.17%); and (5) standard curve (σ_standard_curve = 0.42%). So the calculated σ and density of Alq₃ thin film was found to be 0.71% and 1.31 ± 0.01 g/cm³, respectively.

The method described here is a simple and sensitive way for achieving thin-film density. However, it is not suitable for some of the organic materials, because this method requires thermal and morphological stabilities to form good-quality thin films by vacuum deposition, reasonable solubility in or-
ganic solvent (>0.01 mg/ml), and strong absorption in the UV-visible region for the materials. As shown in Fig. 1, a series of phenanthrolines, Phen, DMPhen, BPhen, and BCP, with similar chemical structure, were used in this study and this method was found to be suitable only for BPhen and BCP. Phen with a decomposition temperature \( T_d \) of 106 °C could not be deposited as a thin film due to its low thermal stability. DMPhen exhibits good thermal stability \( T_d = 305 \) °C, presumably higher density than the metal-free H\(_2\)TPP. Except for H\(_2\)TPP, the calculated densities of the organic thin films are slightly lower than that of organic single crystals (Table I), probably due to the better alignment and packing of molecules in single crystals than those in amorphous films.

**IV. CONCLUSION**

In this study, we have demonstrated an accurate and sensitive method to measure the thin-film density of small-molecular organic materials. Using this method, the calculated \( \sigma \) and density of Alq\(_3\) thin film was found to be 0.71% and 1.31±0.01 g/cm\(^3\), respectively (more detailed information listed in Table I). The results reveal that the thin-film density of these organic materials is not sensitive to vacuum pressure and thin-film growth rate, but strongly depends on their chemical structure and molecular weight, similar to that of metals. Among these organic materials, PtTPP and CuPc have higher density, which can be attributed to the close stacking of essentially planar PtTPP and CuPc molecules.

### Table I. Density of 200-nm-thick organic materials (0.5±1.0 Å/s at 1.0×10\(^{-6}\) Torr).

<table>
<thead>
<tr>
<th>Solvent</th>
<th>( \lambda_{\text{max}} ) (nm)</th>
<th>Standard curve</th>
<th>Molecular weight (g/mol)</th>
<th>( \rho^c ) (g/cm(^3))</th>
<th>( \rho^d ) (g/cm(^3))</th>
</tr>
</thead>
<tbody>
<tr>
<td>BPhen</td>
<td>CHCl(_3) 275</td>
<td>( A = 0.00110 + 117 \times c_m )</td>
<td>0.9999</td>
<td>332.41</td>
<td>1.22±0.01</td>
</tr>
<tr>
<td>BCP</td>
<td>CHCl(_3) 281</td>
<td>( A = 0.001 25 + 111 \times c_m )</td>
<td>0.9999</td>
<td>360.45</td>
<td>1.12±0.01</td>
</tr>
<tr>
<td>Alq(_3)</td>
<td>CHCl(_3) 387</td>
<td>( A = 0.003 10 + 15.7 \times c_m )</td>
<td>0.9999</td>
<td>459.43</td>
<td>1.31±0.01</td>
</tr>
<tr>
<td>CBP</td>
<td>CHCl(_3) 319</td>
<td>( A = 0.001 17 + 60.6 \times c_m )</td>
<td>0.9994</td>
<td>484.59</td>
<td>1.18±0.01</td>
</tr>
<tr>
<td>TPD</td>
<td>CHCl(_3) 353</td>
<td>( A = 0.002 00 + 70.8 \times c_m )</td>
<td>0.9999</td>
<td>516.67</td>
<td>1.08±0.01</td>
</tr>
<tr>
<td>CuPc</td>
<td>PhCl(_2) 475</td>
<td>( A = 0.005 65 + 18.1 \times c_m )</td>
<td>0.9980</td>
<td>576.07</td>
<td>1.54±0.02</td>
</tr>
<tr>
<td>NPB</td>
<td>CHCl(_3) 341</td>
<td>( A = 0.008 65 + 66.4 \times c_m )</td>
<td>0.9999</td>
<td>588.74</td>
<td>1.19±0.01</td>
</tr>
<tr>
<td>H(_2)TPP</td>
<td>CHCl(_3) 418</td>
<td>( A = 0.004 06 + 714 \times c_m )</td>
<td>0.9988</td>
<td>614.74</td>
<td>1.34±0.01</td>
</tr>
<tr>
<td>C(_{60})</td>
<td>PhCl(_2) 333</td>
<td>( A = 0.005 76 + 68.9 \times c_m )</td>
<td>0.9986</td>
<td>720.66</td>
<td>1.46±0.02</td>
</tr>
<tr>
<td>PtTPP</td>
<td>CHCl(_3) 402</td>
<td>( A = 0.007 42 + 364 \times c_m )</td>
<td>0.9998</td>
<td>807.8</td>
<td>1.67±0.02</td>
</tr>
</tbody>
</table>

\( c_m \) is the mass concentration in mg/ml.

\( \rho^c \) is thin-film density calculated by this study.

\( \rho^d \) is single-crystal density from other references.

\( A \) is the mass concentration in mg/ml.

\( \lambda_{\text{max}} \) is the wavelength at the maximum absorbance in nm.

\( R \) is the correlation coefficient of the linear fit.

\( \sigma \) is the standard deviation of the linear fit.

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**FIG. 5. Density of organic materials vs their molecular weight.**
with a short intermolecular face-to-face distance. Finally, the proposed method could also be adopted to measure the density of polymer thin films, which could be prepared by spin coating or printing.

ACKNOWLEDGMENTS

This work is supported by the University Development Fund (Nanotechnology Research Institute, Project No. 00600009) of The University of Hong Kong, and RGC of HKSAR, China (Project No. HKU 7158/04E).